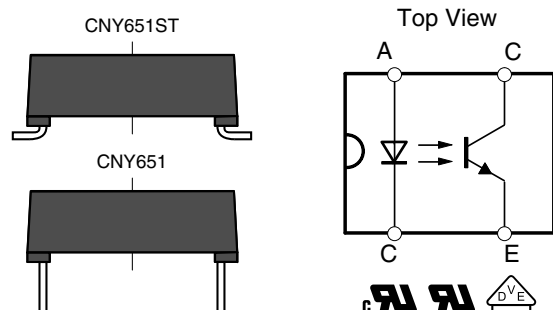


Optocoupler, Phototransistor Output, Very High Isolation Voltage



FEATURES

- Rated recurring peak voltage (repetitive)
 $V_{IORM} = 1450 V_{peak}$
- Thickness through insulation ≥ 3 mm
- Creepage current resistance according to VDE 0303 / IEC 60112 comparative tracking index: **CTI ≥ 475**
- Moisture sensitivity level MSL4
 - Follow defined storage and soldering requirements for CNY651ST devices
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The CNY651 Series are high isolation voltage TH and SMD version optocouplers consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin plastic package.

The single components are mounted opposite one another, providing a distance between input and output for highest safety requirements of > 3 mm.

VDE STANDARDS

These couplers perform safety functions according to the following equipment standards:

- DIN EN 60747-5-5 (VDE 0884-5)**
Optocoupler for electrical safety requirements

APPLICATIONS

- Solar and wind power diagnostic, monitoring, and communication equipment
- Welding equipment
- High voltage motors
- Switch-mode power supplies
- Line receiver
- Computer peripheral interface
- Microprocessor system interface
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
 - for appl. class I to IV at mains voltage ≤ 300 V
 - for appl. class I to IV at mains voltage ≤ 600 V
 - for appl. class I to III at mains voltage ≤ 1000 V according to DIN EN 60747-5-5 (VDE 0884-5)

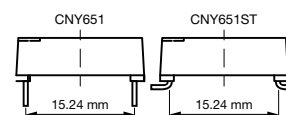
AGENCY APPROVALS

Safety application model number covering all products in this datasheet is CNY651. This model number should be used when consulting safety agency documents.

- [UL / cUL 1577](#)
- [DIN EN 60747-5-5 \(VDE 0884-5\)](#)

ORDERING INFORMATION

C	N	Y	6	5	1	X	X	X	S	T
PART NUMBER				PACKAGE OPTION		CTR BIN				



AGENCY CERTIFIED/PACKAGE	CTR (%)	
	5 mA	
UL, cUL, VDE	50 to 150	100 to 300
DIP-4 HV, 600 mil high isolation distance	-	CNY651AGR
SMD-4 HV, 600 mil high isolation distance	CNY651AYST	CNY651AGRST

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	5	V
Forward current		I_F	75	mA
Forward surge current	$t_p \leq 10\text{ }\mu\text{s}$	I_{FSM}	1.5	A
Power dissipation		P_{diss}	120	mW
Junction temperature		T_j	125	$^{\circ}\text{C}$
OUTPUT				
Collector emitter voltage		V_{CEO}	32	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10\text{ ms}$	I_{CM}	100	mA
Power dissipation		P_{diss}	130	mW
Junction temperature		T_j	125	$^{\circ}\text{C}$
COUPLER				
Total power dissipation		P_{tot}	250	mW
Ambient temperature range		T_{amb}	-40 to +110	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	-40 to +110	$^{\circ}\text{C}$
Soldering temperature for DIP devices	2 mm from case, $\leq 10\text{ s}$	T_{sld}	260	$^{\circ}\text{C}$
Soldering temperature for SMD devices	Please see Fig. 21	T_{sld}	245	$^{\circ}\text{C}$

Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability

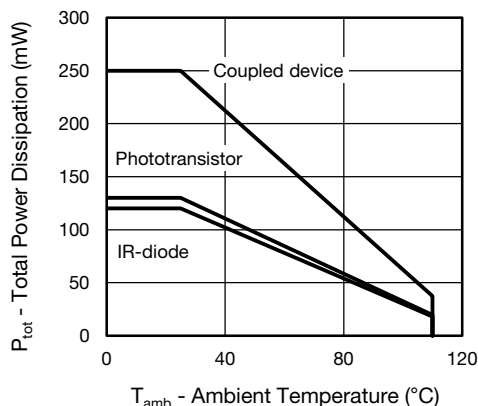


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 50\text{ mA}$	V_F	-	1.32	1.6	V
Junction capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$	C_j	-	50	-	pF
OUTPUT						
Collector emitter voltage	$I_C = 1\text{ mA}$	V_{CEO}	32	-	-	V
Emitter collector voltage	$I_E = 100\text{ }\mu\text{A}$	V_{ECO}	7	-	-	V
Collector emitter leakage current	$V_{CE} = 20\text{ V}, I_F = 0\text{ mA}$	I_{CEO}	-	-	200	nA

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER						
Collector emitter saturation voltage	$I_F = 10\text{ mA}$, $I_C = 1\text{ mA}$	V_{CEsat}	-	-	0.3	V
Cut-off frequency	$V_{CE} = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	f_c	-	110	-	kHz
Coupling capacitance	$f = 1\text{ MHz}$	C_k	-	0.3	-	pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	BIN	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$V_{CE} = 5\text{ V}$, $I_F = 5\text{ mA}$	AY.	CTR	50	-	150	%
		AGR.	CTR	100	-	300	%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$, (see Fig. 3)	t_d	-	2.6	-	μs
Rise time	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$, (see Fig. 3)	t_r	-	2.4	-	μs
Fall time	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$, (see Fig. 3)	t_f	-	2.7	-	μs
Storage time	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$, (see Fig. 3)	t_s	-	0.3	-	μs
Turn-on time	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$, (see Fig. 3)	t_{on}	-	5	-	μs
Turn-off time	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$, (see Fig. 3)	t_{off}	-	3	-	μs
Turn-on time	$V_S = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 1\text{ k}\Omega$, (see Fig. 4)	t_{on}	-	25	-	μs
Turn-off time	$V_S = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 1\text{ k}\Omega$, (see Fig. 4)	t_{off}	-	42.5	-	μs

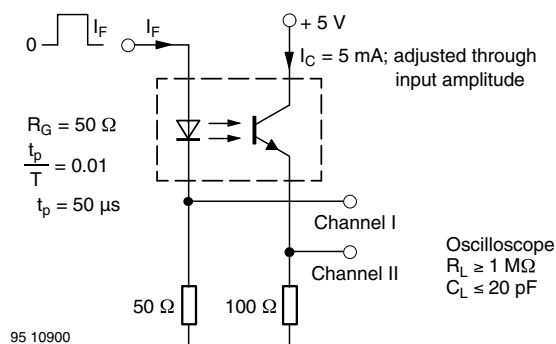


Fig. 2 - Test Circuit, Non-Saturated Operation

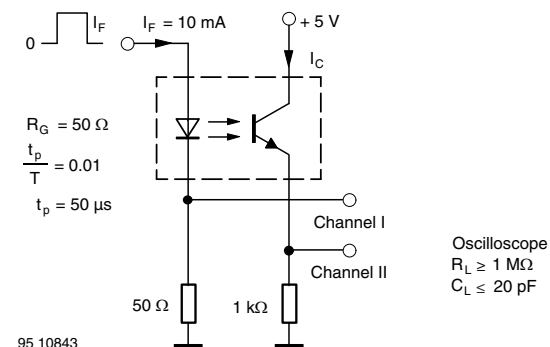


Fig. 3 - Test Circuit, Saturated Operation

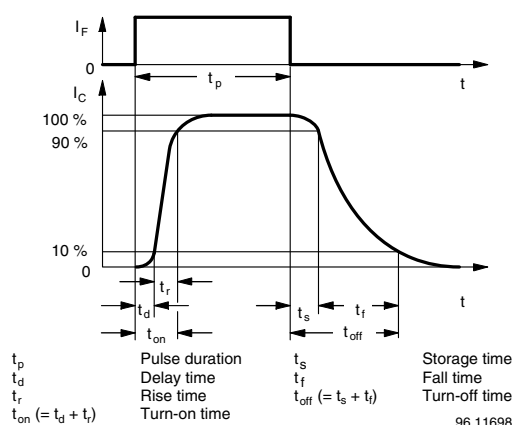


Fig. 4 - Switching Times

SAFETY AND INSULATION RATED PARAMETERS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		40 / 110 / 21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	475	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V_{ISO}	8200	V_{RMS}
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V_{ISO}	13 900	V_{peak}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V_{IOTM}	12 000	V_{peak}
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V_{IORM}	1450	V_{peak}
Isolation resistance	$T_{amb} = 25\text{ }^{\circ}\text{C}$, $V_{IO} = 500\text{ V}$	R_{IO}	$\geq 10^{12}$	Ω
	$T_{amb} = 110\text{ }^{\circ}\text{C}$, $V_{IO} = 500\text{ V}$	R_{IO}	$\geq 10^{11}$	Ω
	$T_{amb} = T_S$, $V_{IO} = 500\text{ V}$	R_{IO}	$\geq 10^9$	Ω
Output safety power		P_{SO}	250	mW
Input safety current		I_{SI}	120	mA
Input safety temperature		T_S	150	$^{\circ}\text{C}$
Creepage distance			≥ 14	mm
Clearance distance			≥ 14	mm
Insulation thickness		DTI	≥ 3	mm
Input to output test voltage, method B	$V_{IORM} \times 1.875 = V_{PR}$, 100 % production test with $t_M = 1\text{ s}$, partial discharge $< 5\text{ pC}$	V_{PR}	3375	V_{peak}
Input to output test voltage, method A	$V_{IORM} \times 1.6 = V_{PR}$, 100 % sample test with $t_M = 10\text{ s}$, partial discharge $< 5\text{ pC}$	V_{PR}	2880	V_{peak}

Note

- According to DIN EN 60747-5-5 (see Fig. 6). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits

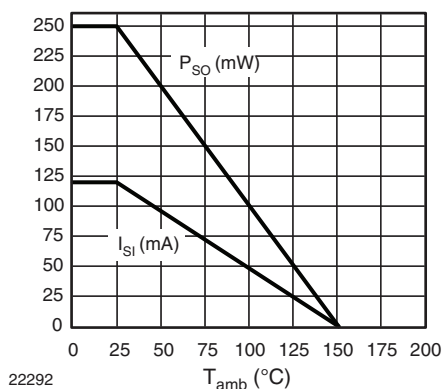


Fig. 5 - Safety Derating Diagram

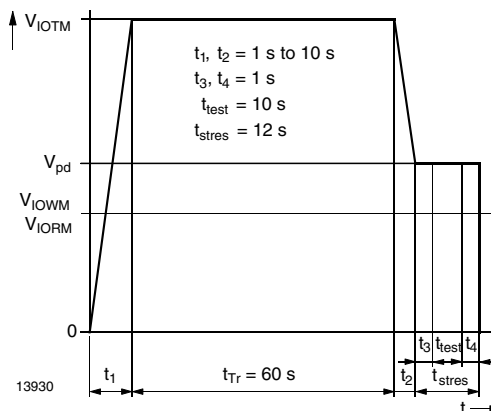


Fig. 6 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5 (VDE 0884-5); IEC60747-5-5

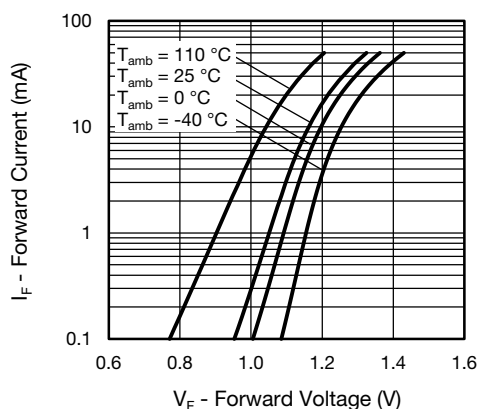
TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


Fig. 7 - Forward Current vs. Forward Voltage

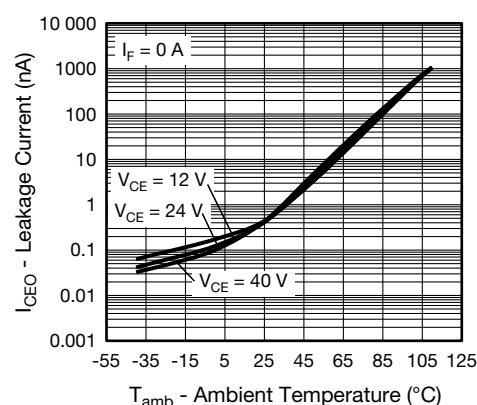


Fig. 10 - Leakage Current vs. Ambient Temperature

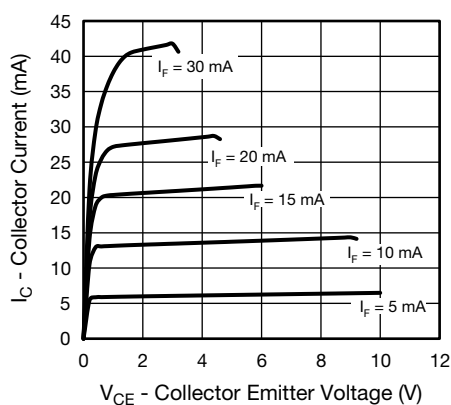


Fig. 8 - Collector Current vs. Collector Emitter Voltage (NS)

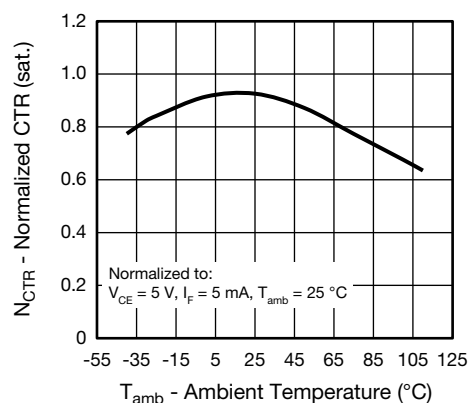


Fig. 11 - Normalized CTR (saturated) vs. Ambient Temperature

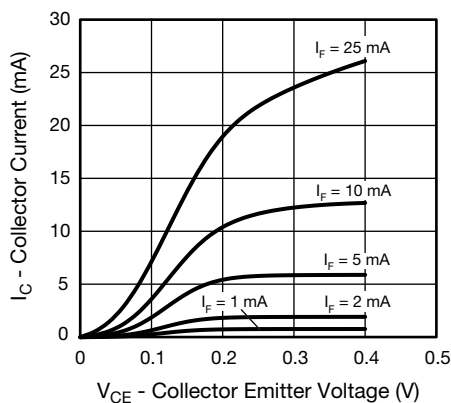


Fig. 9 - Collector Current vs. Collector Emitter Voltage

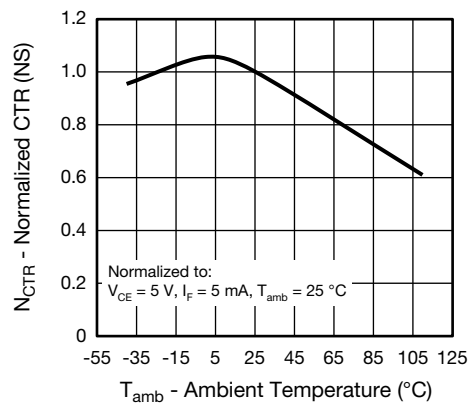


Fig. 12 - Normalized CTR (non-saturated) vs. Ambient Temperature

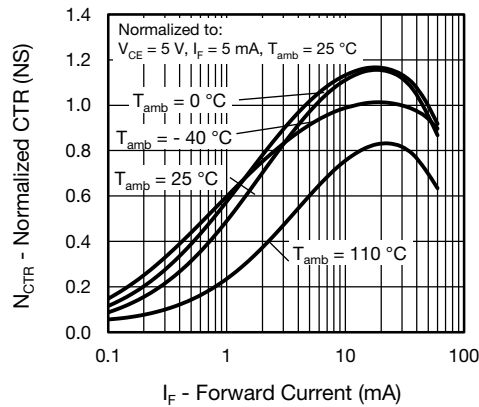


Fig. 13 - Normalized CTR (non-saturated) vs. Forward Current

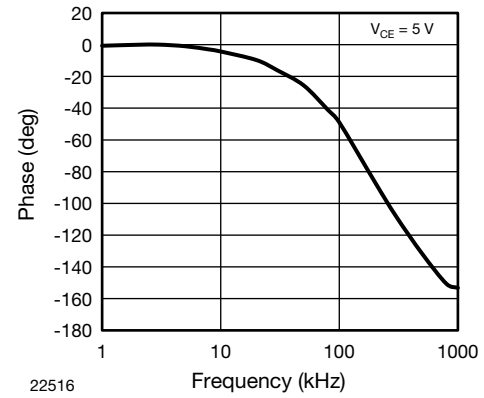


Fig. 16 - Phase Angle vs. F_{CTR}

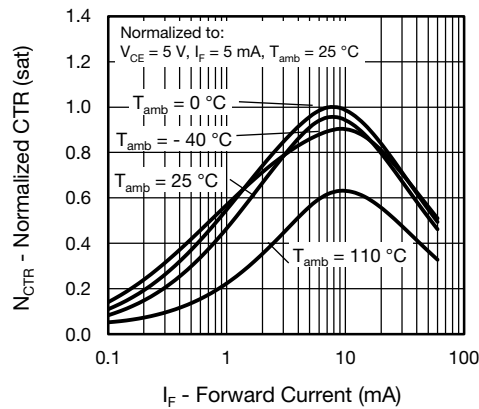


Fig. 14 - Normalized CTR (saturated) vs. Forward Current

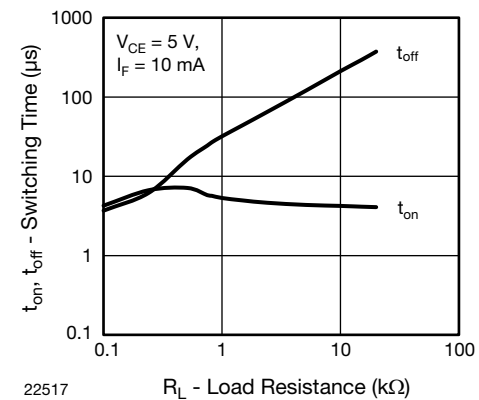


Fig. 17 - Switching Time vs. Load Resistance

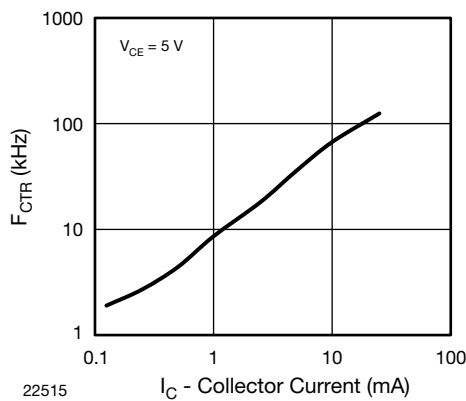
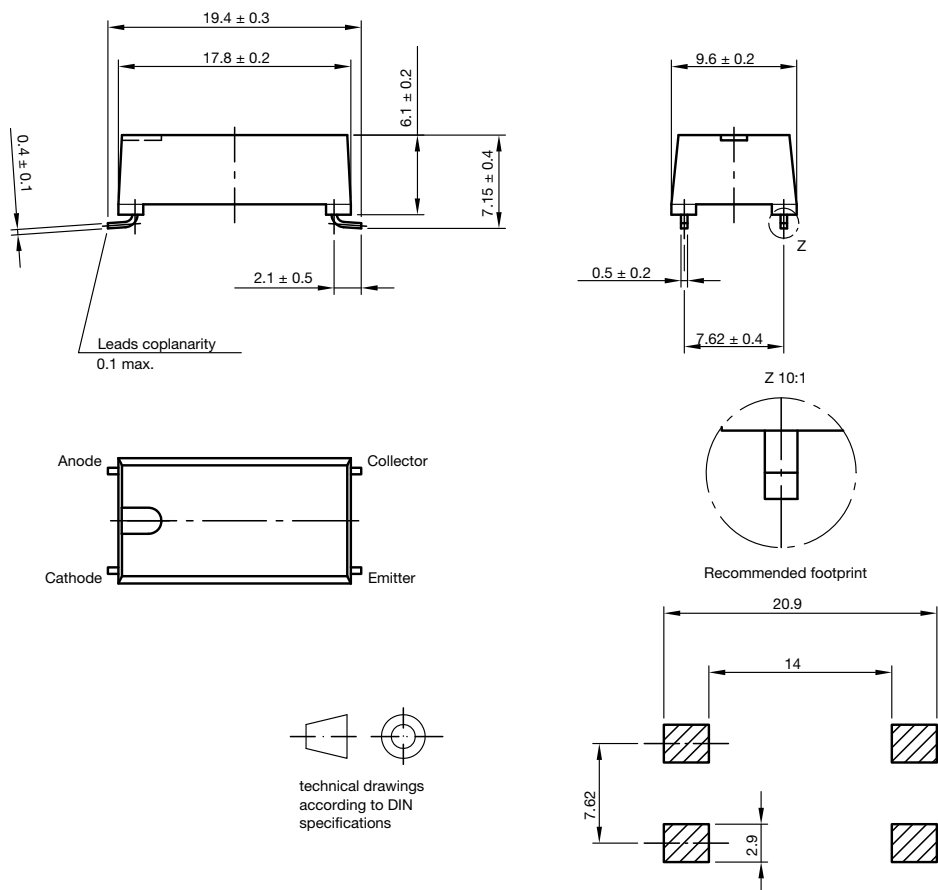
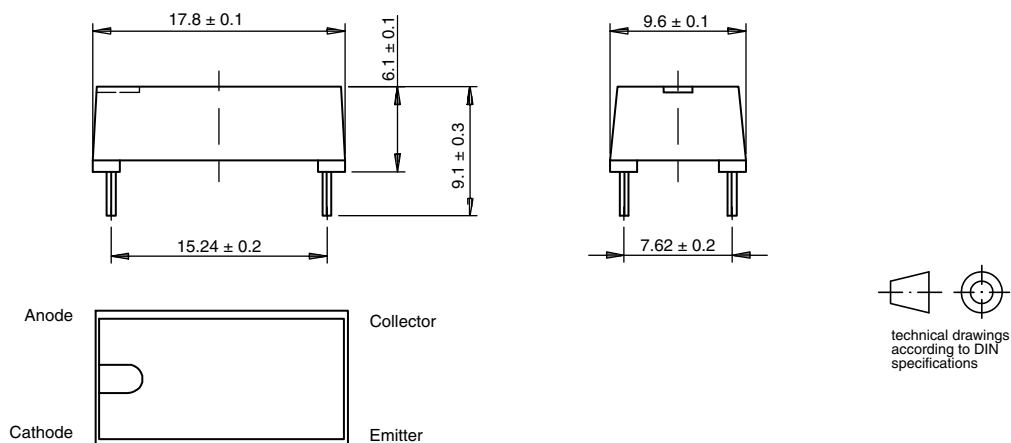


Fig. 15 - F_{CTR} vs. Collector Current

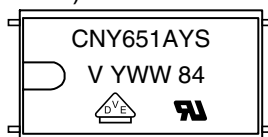
PACKAGE DIMENSIONS in millimeters FOR CNY651A...ST



PACKAGE DIMENSIONS in millimeters FOR CNY651A...



PACKAGE MARKING (Example of CNY651AYST)



Note

- The "T" at the end of the product designation is not marked on the package

TUBE AND TAPE INFORMATION

TUBE INFORMATION			
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX
CNY651	30	35	1050

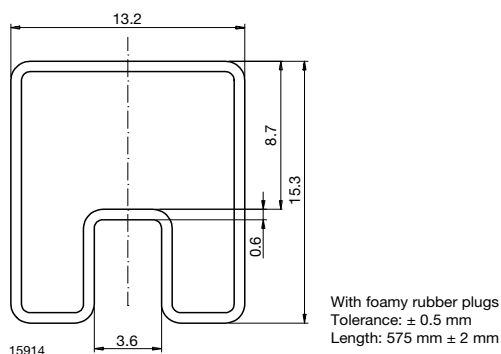
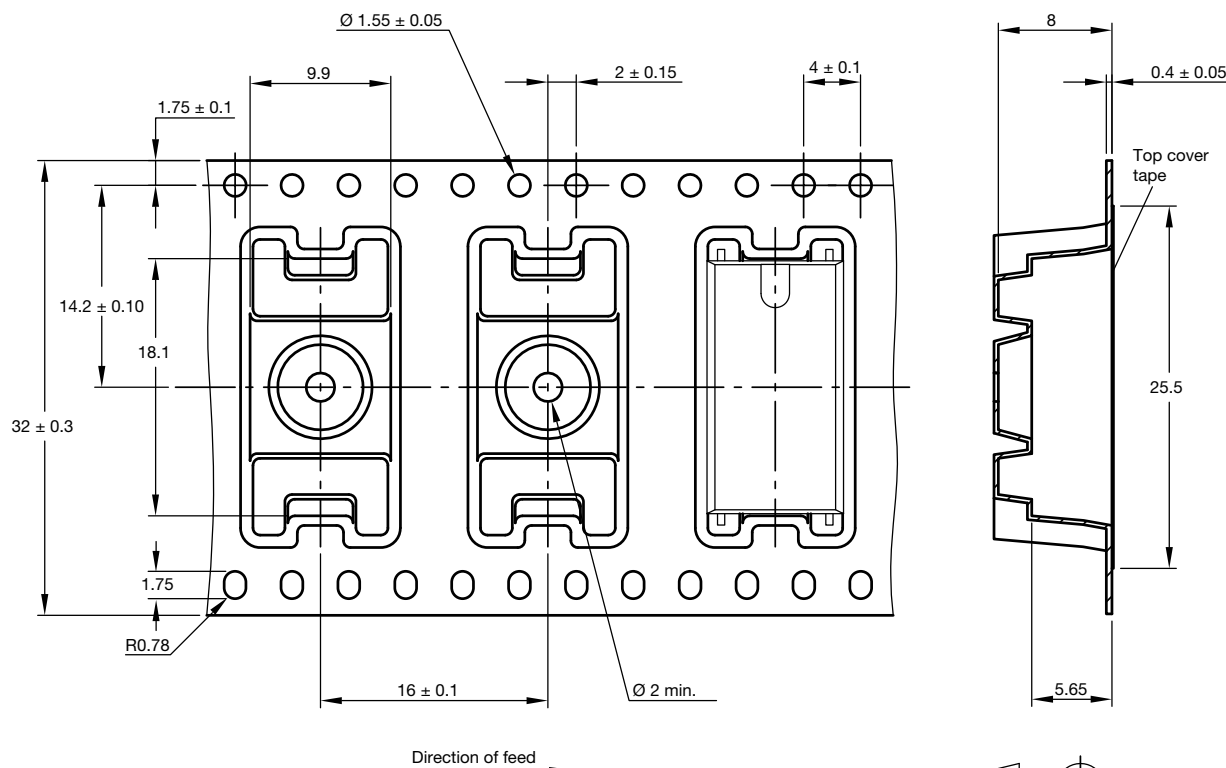
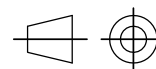


Fig. 18 - CNY651

TAPE DIMENSIONS in millimeters **FOR CNY651A...ST**


Leader (start) min. 400 mm without devices
Trailer (end) min. 200 mm without devices
Drawing-No.: 9.700-5376.01-4
Issue: 1; 23.05.11



technical drawings
according to DIN
specifications

TAPE AND REEL INFORMATION			
TYPE	UNITS/REEL	REELS/BOX	UNITS/BOX
CNY651ST	400	2	800

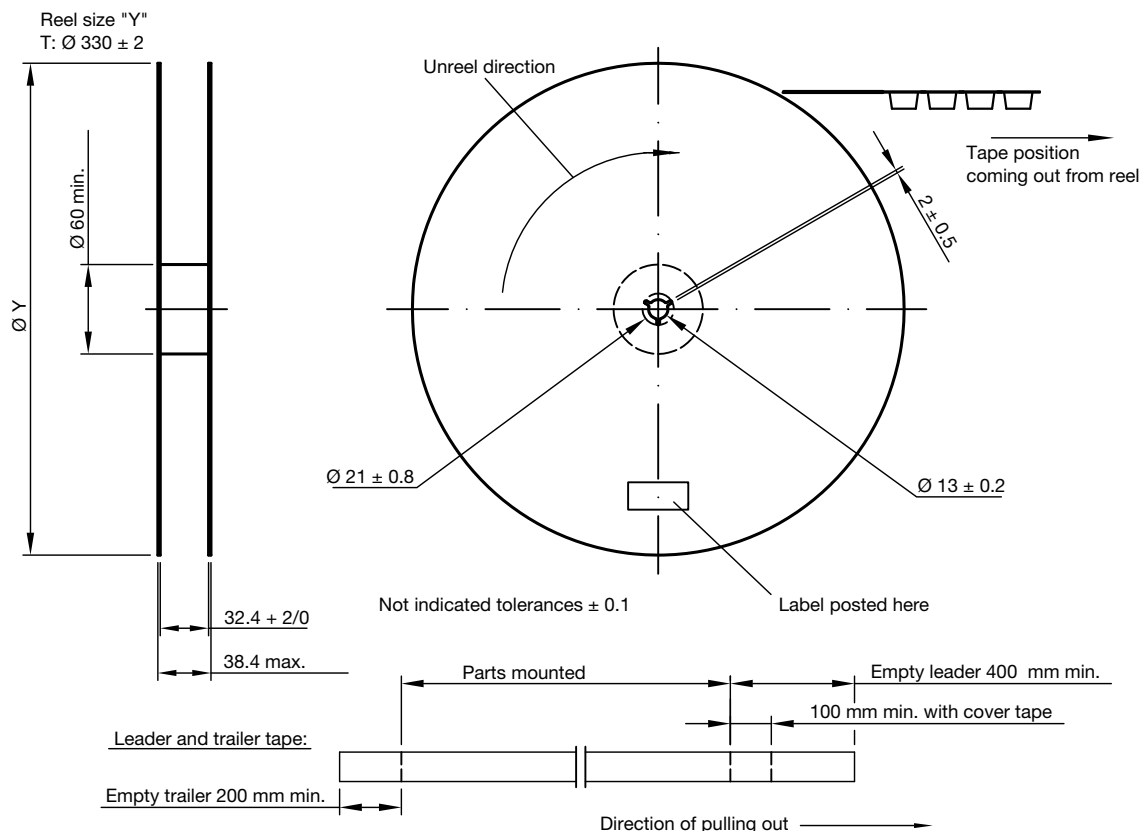
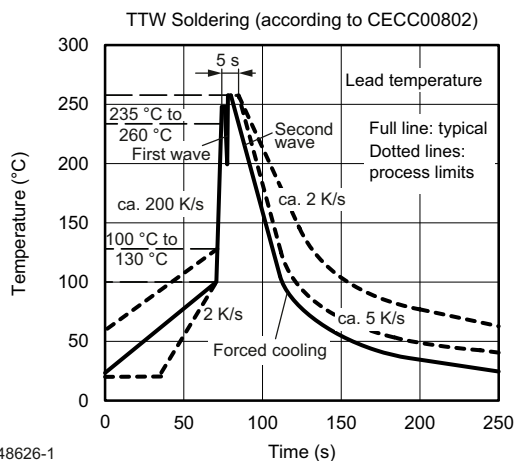
REEL DIMENSIONS in millimeters


Fig. 19 - 400 Units per Reel, 2 Reels per Box

SOLDER PROFILES


948626-1

Fig. 20 - Recommended Wave Soldering Double Wave Profile for DIP Devices

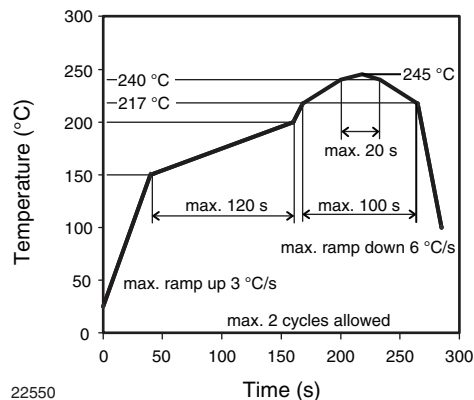


Fig. 21 - Recommended Lead (Pb)-free Reflow Solder Profile for SMD Devices



SOLDERING GUIDELINES

Soldering Condition

The CNY651AxST are lead (Pb)-free devices. They are suitable for reflow soldering. However due to large package size, the peak package body temperature should not go above 245 °C.

Drypack

These devices have a moisture sensitivity level MSL4 thus they are packed in moisture barrier bags (MBB) to prevent moisture absorption during transportation and storage. Each bag contains a desiccant bag.

Floor Life

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 72 h

Conditions: $T_{amb} < 30\text{ °C}$, $RH < 60\%$

Moisture sensitivity level 4, according to J-STD-020.

Drying

In case of moisture absorption devices should be baked before soldering according to the recommended conditions shown below

48 h at $125\text{ °C} \pm 5\text{ °C}$, $RH < 5\%$

(Not suitable for tape and reel)

In case the floor time has not exceeded 10 days the units can be baked in tape and reel according to the following conditions

168 h at $60\text{ °C} \pm 5\text{ °C}$, $RH < 5\%$

(Not suitable, if the floor time was exceeded by more than 10 days, or the allowed factory condition is exceeded)

CNY651 - DIP version device cannot go through reflow soldering hence wave soldering should be used. See absolute maximum ratings for soldering specifications.



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